



For MOSFET: $g_m = \sqrt{2\beta I_{DQ}}$ $r_{gs} = \infty$

$d \leftrightarrow c, s \leftrightarrow e, b \leftrightarrow g$

$(\beta_F = \infty), (r_{gs} \equiv r_{be}), (r_{ds} \equiv r_{ce}), (r_{gi} \equiv r_{bi}), (r_{go} \equiv r_{bo}), (r_{si} \equiv r_{ei}), (r_{so} \equiv r_{eo}), (r_{di} \equiv r_{ci}), (r_{do} \equiv r_{co})$

$$\frac{V_d}{V_g} = -g_m \frac{r_{ds}^2}{g_m r_{so} r_{ds}^2 + r_{ds}^2 + r_{so} r_{ds}} (r_{di} // r_{do})$$

$$r_{di} = r_{ds} + r_{so} + g_m r_{so} r_{ds}$$

$r_{do} \ll r_{di} \text{ and } r_{so} \ll r_{ds} \rightarrow \frac{v_d}{v_g} \cong -\frac{g_m r_{do}}{1 + g_m r_{so}}$

$$\frac{v_s}{v_g} = \frac{g_m r_{so}}{1 + g_m r_{so}} \frac{r_{di}}{r_{di} + r_{do}}$$

$r_{do} \ll r_{di} \rightarrow \frac{v_s}{v_g} \cong \frac{g_m r_{so}}{1 + g_m r_{so}}$

$$\frac{v_d}{v_s} = \left(g_m + \frac{1}{r_{ds}} \right) (r_{ds} // r_{do})$$

$r_{do} \ll r_{ds} \text{ and } \frac{1}{r_{ds}} \ll g_m \rightarrow \frac{v_d}{v_s} \cong g_m r_{do}$

$$r_{si} = \left[\frac{1}{g_m} \frac{(r_{ds} + r_{do})}{\frac{1}{g_m} + r_{ds}} \right]$$

$r_{do} \ll r_{ds} \text{ and } \frac{1}{g_m} \ll r_{ds} \rightarrow r_{si} \cong \frac{1}{g_m}$

$$r_{gi} = \infty$$

$$r_{di} = r_{ds} + g_m r_{so} r_{ds} + r_{so}$$
